**Product data sheet** 

## 1. General description

Dual common cathode power Schottky diode in TO252 (DPAK) plastic package.





## 2. Features and benefits

- High junction temperature up to 175 °C
- Low forward voltage drop, negligible switching losses
- High efficiency

# 3. Applications

- · DC to DC converters
- Freewheeling diode
- OR-ing diode
- · Switched mode power supply rectifier

## 4. Quick reference data

### Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values							
Absolute	Absolute maximum rating											
$V_{RRM}$	repetitive peak reverse voltage				V							
$I_{F(AV)}$	average forward current	$\delta$ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 160 °C; per diode; Fig. 1; Fig. 2; Fig. 3				А						
$I_{O(AV)}$	average output current	$\delta$ = 0.5 ; square-wave pulse; $T_{mb} \le 159$ °C; both diodes conducting		10			А					
Symbol	Parameter	Conditions	Notes	Min	Max	Unit						
Static ch	Static characteristics											
V <sub>F</sub>	forward voltage	$I_F = 5 \text{ A}$ ; $T_j = 25 \text{ °C}$ ; per diode; Fig. 6		-	0.83	0.93	V					
I <sub>R</sub>	reverse current	$V_R = 200 \text{ V}$ ; $T_j = 25 \text{ °C}$ ; per diode; Fig. 7; Fig. 8	25 °C; per diode; - 0.03 5				μΑ					

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		
2	K	cathode		A1
3	A2	anode 2		K sym125
mb	К	mounting base; connected to cathode		ojiin Eu

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package name	Orderable part number	Packing method	Small packing guantity	Package version	Package issue date
WN3S10S200CDT	TO252	WN3S10S200CDTJ	Reel	2500	TO252d	07-Sep-2022

# 7. Marking

### **Table 4. Marking codes**

Type number	Marking codes
WN3S10S200CDT	WN3S10S 200CDT

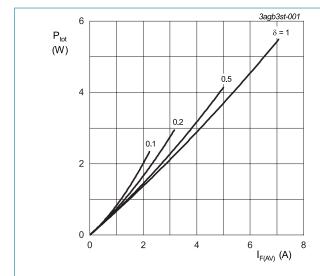
# 8. Limiting values

## **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

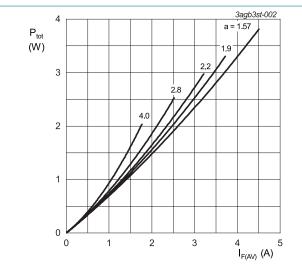
Symbol	Parameter	Conditions	Notes	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage			200	V
$V_{RWM}$	crest working reverse voltage			200	V
$V_R$	reverse voltage	DC		200	V
$I_{F(AV)}$	average forward current	$δ$ = 0.5 ; square-wave pulse; $T_{mb} \le 160$ °C; per diode; Fig. 1; Fig. 2; Fig. 3		5	А
$I_{O(AV)}$	average output current	$\delta$ = 0.5; square-wave pulse; $T_{mb} \le 159$ °C; both diodes conducting		10	А
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; Fig. 4		130	А
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		143	А
T <sub>stg</sub>	storage temperature			-40 to 175	°C
T <sub>j</sub>	junction temperature		[1]	-40 to 175	°C

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient:  $dP_{tot}/dT_j < 1/R_{th(j-a)}$ 



 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$  $V_o = 0.651 \text{ V}; R_s = 0.0177 \Omega$ 

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values; per diode



a = form factor =  $I_{F(RMS)}$  /  $I_{F(AV)}$ V<sub>o</sub> = 0.651 V; R<sub>s</sub> = 0.0177  $\Omega$ 

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values; per diode

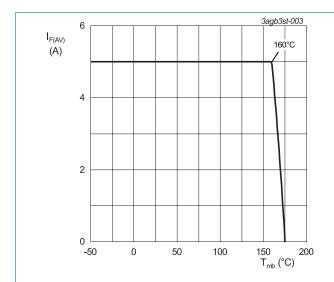


Fig. 3. Average forward current as a function of mounting base temperature; maximum values; per diode

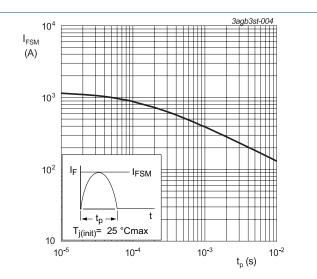


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values; per diode

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance	per diode; Fig. 5		-	-	3.7	K/W
	from junction to mounting base	both diodes conducting		-	-	1.9	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air		-	50	-	K/W

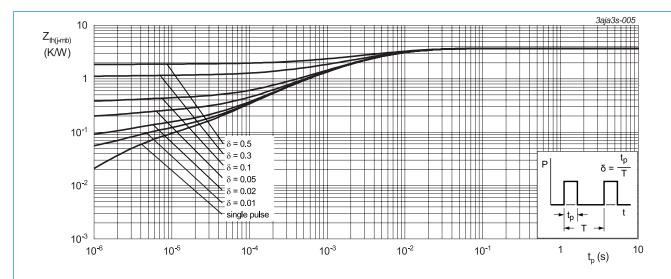


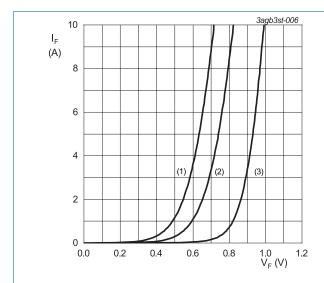
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; maximum values; per diode

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## 10. Characteristics

### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
$V_{F}$	forward voltage	$I_F = 5 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.83	0.93	V
		I <sub>F</sub> = 5 A; T <sub>j</sub> = 125 °C; per diode; <u>Fig. 6</u>		-	0.70	-	V
I <sub>R</sub> reverse current		$V_R = 200 \text{ V}; T_j = 25 ^{\circ}\text{C}; \text{ per diode}; $ Fig. 7; Fig. 8		-	0.03	5	μА
		$V_R = 200 \text{ V}; T_j = 125 ^{\circ}\text{C}; \text{ per diode}; $ Fig. 7; Fig. 8		-	0.04	-	mA



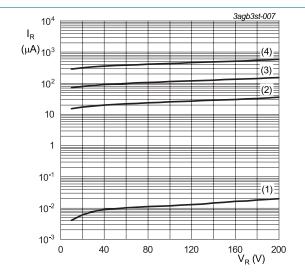
 $V_o = 0.651 \text{ V}; R_s = 0.0177 \Omega$ 

(1)  $T_i = 175$  °C; typical values

(2) T<sub>j</sub> = 175 °C; maximum values

(3) T<sub>i</sub> = 25 °C; maximum values

Fig. 6. Forward current as a function of forward voltage; per diode



(1) T<sub>i</sub> = 25 °C; typical values

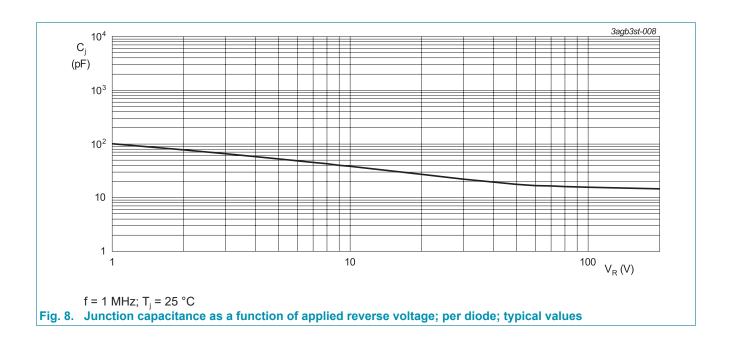
(2) T<sub>i</sub> = 125 °C; typical values

(3)  $T_i = 150$  °C; typical values

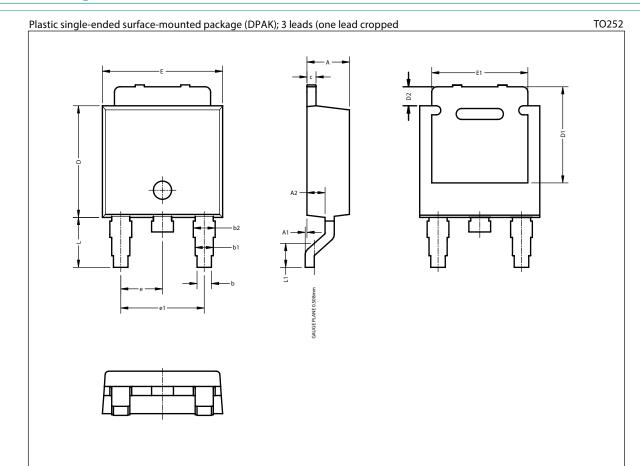
(4) T<sub>i</sub> = 175 °C; typical values

Fig. 7. Reverse leakage current as a function of reverse voltage; per diode; typical values

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# 11. Package outline



### Note:

1. All dimensions do not include mold flash & gate remain and metal protrusion.

Unit	t	Α	A1	<b>A</b> 2	b	b1	b2	С	D	D1	D2	E	E1	е	e1	L	L1
	min nom	2.16	0.00	0.90	0.70	0.86	1.06	0.46	5.97	5.05	0.98	6.45	5.20	2.30	4.60	2.60	1.25
		2.41	0.10	1.10	0.90	1.11	1.32	0.58	6.22	5.35	1.18	6.75	5.40			2.90	1.65

## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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